TENTATIVE

TOSHIBA INFRARED LED GaAlas INFRARED EMITTER

TLN223

INFRARED LED FOR SPACE-OPTICAL-TRANSMISSION

• High radiant power : Po=18mW (TYP.) at I_F=50mA

• Narrow radiant pattern : $\theta = \pm 13^{\circ}$ (TYP.)

• High speed response : t_r, t_f=30ns (TYP.)

• A light source for remote control.

• Wireless AV-signal transmission purpose.

• High speed data transmission purpose.

MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|-----------------------------|-------------------|---------------|----------------------|
| Forward Current | $I_{\mathbf{F}}$ | 100 | mA |
| Pulse Forward Current | I_{FP} | 1000 (Note:1) | mA |
| Power Dissipation | P_{D} | 220 | mW |
| Reverse Voltage | v_{R} | 4 | V |
| Operating temperature Range | ${ m T_{opr}}$ | -25~85 | °C |
| Storage Temperature Range | $ m T_{stg}$ | -30~100 | $^{\circ}\mathrm{C}$ |
| Soldering Temperature (5s) | T_{sol} | 260 | $^{\circ}\mathrm{C}$ |

(Note:1) Frequency=100kHz, duty=1%

* (Includes 1 2 resin-mold portion) (): REFERENCE VALUE JEDEC — EIAJ — TOSHIBA 4-5V3

PIN CONNECTION

1 ○ → 2

ANODE
 CATHODE

OPTO-ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|----------------------------|---------------------------------|---|------|------|--------------|----------------|
| Forward Voltage | $V_{\mathbf{F}}$ | I _F =100mA | _ | 1.8 | 2.2 | V |
| Reverse Current | I_{R} | $V_R=4V$ | _ | _ | 60 | μ A |
| Radiant Power | PO | $I_{ m F}\!=\!50{ m mA}$ | 14 | 18 | _ | mW |
| Radiant Intensity | $I_{\mathbf{E}}$ | $I_{\rm F} = 50 { m mA}$ | _ | 40 | - | mW/sr |
| Rise Time, Fall Time | t _r , t _f | $I_{\mathrm{FP}} = 100 \mathrm{mA}, P_{\mathrm{W}} = 100 \mathrm{ns}$ | _ | 30 | _ | ns |
| Cut-off Frequency (Note:2) | f_c | $I_{\rm F} = 50 {\rm mA_{DC}} + 5 {\rm mA_{P-P}}$ | 10 | 15 | - | MHz |
| Capacitance | $\mathrm{c_{T}}$ | $V_R = 0$, $f = 1MHz$ | _ | 110 | _ | рF |
| Peak Emission Wavelength | $\lambda_{\mathbf{P}}$ | $I_{\mathbf{F}} = 50 \text{mA}$ | 830 | 870 | 900 | nm |
| Spectral Line Half Width | Δλ | $I_{ m F}\!=\!50{ m mA}$ | _ | 50 | _ | nm |
| Half Value Angle | $\theta_{\frac{1}{2}}$ | $I_{ m F}\!=\!50{ m mA}$ | _ | ±13 | _ | ٥ |

(Note:2) Frequency when modulation light power decreases by 3dB from 1MHz.

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PRECAUTION

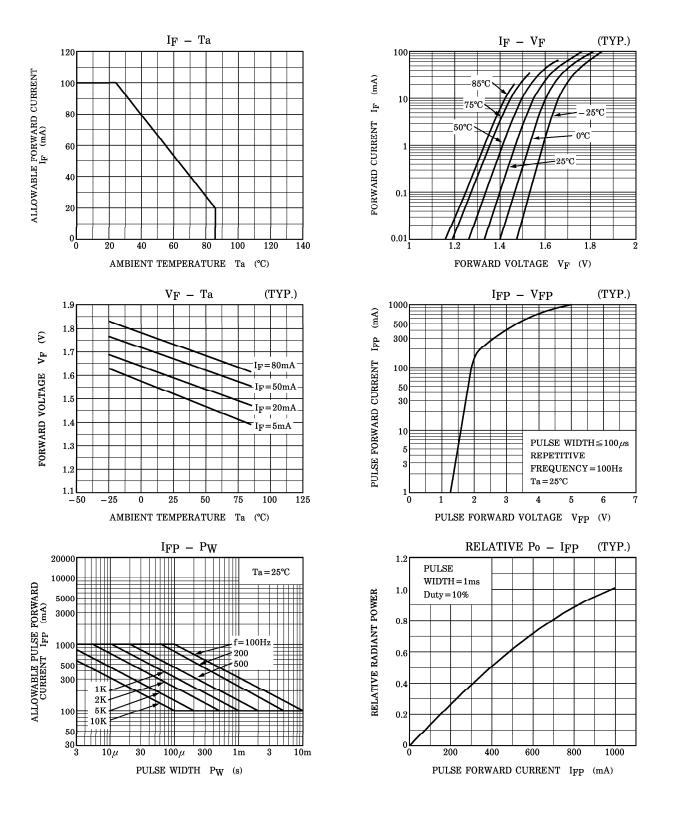
Please be careful of the followings.

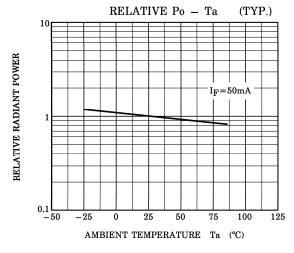
- Soldering shall be performed at the top portion from the lead stopper.
- When the lead is formed, the lead shall be formed at the top portion of the stopper without leaving forming stress to the body of the device. Soldering shall be performed after lead forming.

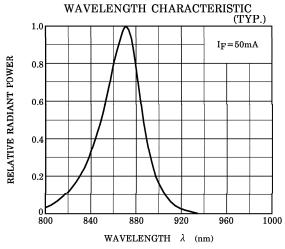
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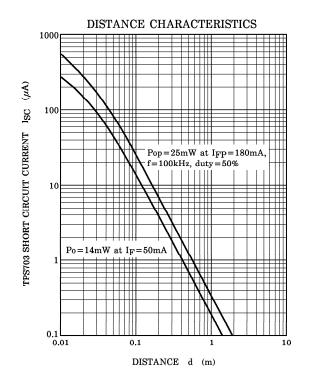
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RADIATION PATTERN (TYP.) $\label{eq:Ta=25°C} {\rm Ta=25°C}$

